



# Article Photoelectrochemical Performance of a $CuBi_2O_4$ Photocathode with $H_2O_2$ as a Scavenger

Zohreh Masoumi <sup>1</sup>, Mahdi Tayebi <sup>2</sup>, S. Ahmad Masoumi Lari <sup>3</sup>, Bongkuk Seo <sup>4</sup>, Choong-Sun Lim <sup>4</sup>, Hyeon-Gook Kim <sup>4</sup>,\*, Daeseung Kyung <sup>1</sup>,\* and Meysam Tayebi <sup>4</sup>,\*

- <sup>1</sup> Department of Civil and Environment Engineering, University of Ulsan, Daehakro 93, Nam-gu, Ulsan 44610, Republic of Korea
- <sup>2</sup> Department of Energy Engineering and Physics, Amirkabir University of Technology, Tehran 15875-4413, Iran
- <sup>3</sup> Department of Biology, York University, Farquharson Life Sciences Building, Ottawa Rd, Toronto, ON M3J 1P3, Canada
- <sup>4</sup> Center for Advanced Specialty Chemical, Division of Specialty and Bio-Based Chemicals Technology, Korea Research Institute of Chemical Technology (KRICT), 45 Jonggaro, Ulsan 44412, Republic of Korea
- \* Correspondence: candoit@krict.re.kr (H.-G.K.); dkyung@ulsan.ac.kr (D.K.); mtayebi@krict.re.kr or mtayebi2900@gmail.com (M.T.)

Abstract: Photoelectrochemical (PEC) water splitting is an eco-friendly method for producing clean and sustainable hydrogen fuels. Compared with the fabrication of solar hydrogen using n-type metal oxide semiconductor photoanodes, that of solar hydrogen using p-type metal oxide semiconductor photocathodes has not been researched as thoroughly. Therefore, this study investigated the effect of drop casting time on the PEC performance of a prepared CuBi<sub>2</sub>O<sub>4</sub> photocathode. XPS, HRTEM, UV-DRS, Raman spectroscopy, XRD, and SEM analyses were used to characterize the prepared CuBi<sub>2</sub>O<sub>4</sub> photocathode. Owing to the high charge separation and transfer, the photocurrent density of the CuBi<sub>2</sub>O<sub>4</sub> photocathode was ~0.6 mA cm<sup>-2</sup> at 0.3 V vs. RHE. The nanoporous CuBi<sub>2</sub>O<sub>4</sub> photocathode exhibited a high photocurrent density of up to 1.2 mA cm<sup>-2</sup> at 0.3 V vs. RHE with H<sub>2</sub>O<sub>2</sub> as a sacrificial agent. Mott–Schottky and impedance measurements were also performed on the CuBi<sub>2</sub>O<sub>4</sub> photocathode to estimate its acceptor density and charge-transfer resistance.

Keywords: PEC water splitting; CuBi<sub>2</sub>o<sub>4</sub>; photocathode; charge transport; accepter density

# 1. Introduction

PEC water splitting is an attractive renewable energy conversion and storage method that uses sunlight to transform water into hydrogen [1–6]. In this process, n-type semiconductors are used as photoanodes for water oxidation, whereas p-type semiconductors, such as Cu<sub>2</sub>O [7], GaN [8], NiO [9], and the ternary oxides CaFe<sub>2</sub>O<sub>4</sub> [10], CuNb<sub>3</sub>O<sub>8</sub> [11], CuFeO<sub>2</sub> [12], LaFeO<sub>3</sub> [13], and CuBi<sub>2</sub>O<sub>4</sub> [14], can be applied as possible photocathode materials. Among the many p-type semiconductors, copper-based ternary oxides (CuBi<sub>2</sub>O<sub>4</sub>), which possess several attractive properties, are promising candidates for PEC water splitting. The favorable absorption energy bandgap of p-type CuBi<sub>2</sub>O<sub>4</sub> (CBO) photocathodes, which are active in visible light, ranges between 1.5 and 1.8 eV and has received increasing attention [15–20].

CBO, a powder-type photocatalyst, has been synthesized via the hydrothermal method [21], the sol-gel method [22], solid-state synthesis [23], and metal-organic decomposition [24]. However, only a few studies have focused on fabricating a high-quality thin CBO layer with adequate electrical consistency, a high surface area, and consistent coating. Thus, developing synthesis techniques for preparing high-quality CBO electrodes would be advantageous for addressing this research gap and for enhancing their PEC water splitting.



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**Copyright:** © 2023 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/). Herein, we present a facile and economical casting for fabricating CBO photocathodes with a high surface area.

Most reported porous CBO films have an unstable structure or only partially cover the substrate [25], which typically results in low photocurrent densities. CBO films have been fabricated for PEC water splitting reactions using various synthesis techniques. However, the PEC efficiency of such films may be reduced owing to their irregular nanoporous shape. Increasing the thickness of the nanoporous thin films can minimize the exposure of the substrate to the electrolyte; however, due to restricted charge transfer, this increase in thickness may have an inverse effect on the photocurrent. A simple process for fabricating high-quality nanoporous layers is critical for developing high-performance CBO photocathodes. Herein, a simple drop casting procedure is presented with the optimization thickness of CBO films for energy conversion into PEC photovoltaics.

We optimized the effect of drop casting time on the PEC performance of the prepared  $CuBi_2O_4/FTO$  thin film. The PEC performance was measured to comprehensively explore the influence of the drop casting time. Furthermore, the effect of  $H_2O_2$  as a sacrificial agent on the  $CuBi_2O_4$  photocathode was investigated. Mott–Schottky and electrochemical impedance (EIS) analyses were conducted to study the enhancement of the PEC performance of the CuBi\_2O\_4 photocathodes.

# 2. Experimental Section

# 2.1. Fabrication of CuBi<sub>2</sub>O<sub>4</sub> Photocathodes' Thin Films

The substrate, fluorine-doped tin oxide-coated glass (FTO, 25 mm  $\times$  25 mm  $\times$  2.2 mm, 7 O/sq), was cleaned with deionized water, ethanol, and acetone for 15 min. Initially, 0.058 g of Cu(NO<sub>3</sub>)<sub>2</sub>.3H<sub>2</sub>O was dissolved in ethanol, and 0.243 g of Bi(NO<sub>3</sub>)<sub>3</sub>.5H<sub>2</sub>O was dissolved in acetic acid. Precursor solution-based drop casting processes for fabricating CuBi<sub>2</sub>O<sub>4</sub> photocathodes frequently use acetic acid and ethanol as solvents to dissolve Bi(NO<sub>3</sub>)<sub>3</sub> and Cu(NO<sub>3</sub>)<sub>2</sub>, respectively. CBO photocathodes were fabricated using a low-cost and simple drop casting method. The precursor solution (100 µL) was dropped onto FTO before being placed in a furnace (denoted as #n-CuBi<sub>2</sub>O<sub>4</sub>) for 5 min at 550 °C. Drop casting was performed one, two, and four more times under identical conditions, and the resulting samples were designated as #1-CuBi<sub>2</sub>O<sub>4</sub>, #2-CuBi<sub>2</sub>O<sub>4</sub>, and #4-CuBi<sub>2</sub>O<sub>4</sub>, respectively. All CuBi<sub>2</sub>O<sub>4</sub> photocathodes were calcined for 4 h at 550 °C in a furnace. Figure 1a shows a schematic of the CuBi<sub>2</sub>O<sub>4</sub> photocathode synthesis process and the procedures involved.



**Figure 1.** (a) Fabrication procedure of  $CuBi_2O_4$  photocathodes. SEM images of  $CuBi_2O_4$ . Photocathodes by the drop casting method: (b) #1- $CuBi_2O_4$ , (c) #2- $CuBi_2O_4$ , and (d) #4- $CuBi_2O_4$ .

# 2.2. Photoelectrochemical (PEC) Measurements

The synthesized CBO was utilized as the working electrode, Ag/AgCl was used as the reference electrode, and Pt wire was used as the counter electrode during the PEC measurements, which were performed in a standard three-electrode setup at a scan rate of 10 mV/s. The PEC performance was assessed in an electrolyte solution of 0.5 M Na<sub>2</sub>SO<sub>4</sub> under 100 mW/cm<sup>2</sup> irradiation (AM 1.5) from the front of the photocathode using a 300 W Xe lamp. H<sub>2</sub>O<sub>2</sub> was used as the electron scavenger by adding an appropriate amount of H<sub>2</sub>O<sub>2</sub> to 50 mL of a 0.5M Na<sub>2</sub>SO<sub>4</sub> aqueous electrolyte. A VersaSTAT 3 potentiostat was used to record the PEC characteristics, including the photocurrent, electrochemical impedance, and Mott–Schottky plots. Linear sweep voltammetry (LSV) measurements were performed at a scan rate of 0.02 Vs<sup>-1</sup>. A sinusoidal voltage pulse of an amplitude of 10 mV was applied on a bias potential, with frequencies ranging from 100 kHz to 0.1Hz for the EIS of the photocathodes. The Mott–Schottky measurement was performed in the potential range of 0.7–1.6 V vs. RHE, with frequencies of 1000 Hz. The Ag/AgCl reference potential was converted into RHE using Equation (1):

$$V_{\rm RHE} = V_{\rm Ag/AgCl} + 0.197 + 0.059 \,\,\text{pH} \tag{1}$$

### 3. Results and discussion

### 3.1. Physiochemical and Morphological Properties

Figure 1b shows the SEM image of a  $CuBi_2O_4$  photocathode prepared by one-time drop casting. After one-time drop casting of the  $CuBi_2O_4$  precursor on FTO, the  $CuBi_2O_4$  photocathode was almost transparent and uneven (inset of Figure 1b), indicating that it was not high-quality. As shown in the inset of Figure 1c, the #2-CuBi\_2O\_4 photocathode became dark brown after two-time drop casting, indicating the formation of uniform nanoporous structures. After four-time drop casting (#4-CuBi\_2O\_4), nanoparticles agglomerated on the photocathode surface (Figure 1d). This could be one of the reasons for the lower PEC performance of the #4-CuBi\_2O\_4 photocathode compared with that of #2-CuBi\_2O\_4 [26].

Figure 2a shows the SEM image of the CuBi<sub>2</sub>O<sub>4</sub> photocathode with a nanoporous structure and a nanoparticle size of ~250 nm. The effect of thickness on the PEC performances of the #1-CuBi<sub>2</sub>O<sub>4</sub>, #2-CuBi<sub>2</sub>O<sub>4</sub>, and #4-CuBi<sub>2</sub>O<sub>4</sub> photocathodes was determined (Figure S5). The different drop casting processes conducted one, two, and four times (layers) led to the formation of a thin layer of CuBi<sub>2</sub>O<sub>4</sub> on the substrate with thicknesses of ~450, 650, and 1000 nm, respectively. Increasing the thickness from 450 to 650 nm led to an increase in the photocurrent density. However, the photocurrent decreased when the drop casting process was repeated four times, resulting in a thickness of 1000 nm. Therefore, the best photocurrent density was obtained through the two-time drop casting processes (~650 nm) because the electron–hole pairs generated in the bulk of the films during PEC water splitting recombined before reaching the surface.

Furthermore, the HRTEM image (Figure 2b) shows  $CuBi_2O_4$  with a nanoparticle size of ~250 nm. To illustrate the lattice spacing (the shortest distance between the planes of atoms in a crystal), HRTEM was performed using a fast Fourier transform (Figures 2c and S4). The diffraction planes of the  $CuBi_2O_4$  lattice included 0.35 nm, which matched well with the interplanar spacing of the (211) plane of  $CuBi_2O_4$  [15]. TEM elemental mapping showed that Cu, Bi, and O were uniformly present in the  $CuBi_2O_4$  photocathode (Figure 2d–g).

20 nm





The XRD results confirmed the highly crystalline configuration of the photocathodes with a tetragonal structure of the CuBi<sub>2</sub>O<sub>4</sub> photocathode (JCPDS No. 72–493) [27]. The Raman peaks (Figure S1) observed at 261, 404, and 587 cm<sup>-1</sup> confirmed the presence of a tetragonal CuBi<sub>2</sub>O<sub>4</sub> structure [21,28]. The small peak at 186 cm<sup>-1</sup> was assigned to the Eg mode vibration of Cu–Cu [29]. The full-scan XPS profiles (Bi 4f, Cu 2p, and O 1s), shown in Figures 3b,c and S2, reveal that the #2-CuBi<sub>2</sub>O<sub>4</sub> shows all the components in the photocathode. The Cu 2p XPS profile of the #2-CuBi<sub>2</sub>O<sub>4</sub> photocathode shown in Figure S2a has two main peaks at binding energies of 933.64 and 953.4 eV that are related to Cu 2p3/2 and Cu 2p1/2, respectively [30]. The Bi 4f XPS profile, shown in Figure 3c, has two main peaks at 158.6 and 163.9 eV, corresponding to Bi 4f7/2 and Bi 4f5/2, respectively [31]. Furthermore, as shown in Figure S2b, the O 1s XPS profile has a main peak at 529.4 eV corresponding to lattice oxygen in metal oxides, whereas the smaller peak at 531.1 eV corresponds to the oxygen defect [32]. Figure 3d shows the UV-DRS profile of the CuBi<sub>2</sub>O<sub>4</sub> photocathode, The CuBi<sub>2</sub>O<sub>4</sub> photocathode, The CuBi<sub>2</sub>O<sub>4</sub> photocathode, The Signer 3d shows the UV-DRS profile of the CuBi<sub>2</sub>O<sub>4</sub> photocathode, the oxygen defect [32]. Figure 3d shows the UV-DRS profile of the CuBi<sub>2</sub>O<sub>4</sub> photocathode, consistent with the results of a previous study [17].



**Figure 3.** (a) XRD patterns, (b) XPS full-scan survey, (c) high-resolution XPS peaks for Bi 4f, and (d) band gap of the #2-CuBi<sub>2</sub>O<sub>4</sub> photocathode.

# 3.2. PEC Water Splitting Properties

All samples exhibited negligible dark current densities (Figure 4a,b). Increasing the drop casting time led to an improvement in the photocurrent density of  $CuBi_2O_4$ . However, the photocurrent decreased after four-time drop casting. Therefore, the highest photocurrent density was achieved via two-time drop casting (#2-CuBi\_2O\_4 photocathode), owing to the superior electron–hole separation in the bulk of the CuBi\_2O\_4 photocathode during PEC water splitting.

LSV scans of #1-CuBi<sub>2</sub>O<sub>4</sub>, #2-CuBi<sub>2</sub>O<sub>4</sub>, and #4-CuBi<sub>2</sub>O<sub>4</sub> are shown in Figure 4a. The LSV results indicate a p-type semiconductor in which a cathodic photocurrent was observed [33]. Figure 4a shows that the onset potentials of #1-CuBi<sub>2</sub>O<sub>4</sub>, #2-CuBi<sub>2</sub>O<sub>4</sub>, and #4-CuBi<sub>2</sub>O<sub>4</sub> were ~1.05 V vs. RHE under 100 mW cm<sup>2</sup> illumination. At the optimal drop casting time (#2-CuBi<sub>2</sub>O<sub>4</sub> photocathode), the photocurrent density was ~0.6 mA/cm<sup>2</sup> at 0.3 V vs. RHE. The photocurrent responses (Figure 4c,d) were in good agreement with the LSV and chopped LSV results shown in Figure 4a,b, respectively. Figure 4d shows good photocurrent stability without any significant change in the initial photocurrent for 15 min after four cycles of on–off light under 100 mW/cm<sup>2</sup> illumination.



**Figure 4.** (a) LSV, (b) chopped LSV, (c,d) photocurrent response of the #1-CuBi<sub>2</sub>O<sub>4</sub>, #2-CuBi<sub>2</sub>O<sub>4</sub>, and #4-CuBi<sub>2</sub>O<sub>4</sub> photocathodes. Under 100 mW/cm<sup>2</sup> illumination, the electrolyte was a 0.5 M aqueous solution of Na<sub>2</sub>SO<sub>4</sub>.

# 3.3. Nyquist (Impedance Analysis) and Mott-Schottky Plots

EIS was performed to study the electron–hole transport of the CuBi<sub>2</sub>O<sub>4</sub> photocathodes [34,35]. The resistance of the #2-CuBi<sub>2</sub>O<sub>4</sub> photocathode (R<sub>ct</sub>) was determined from the radius of the semi-circle, which was smaller than that of the #1-CuBi<sub>2</sub>O<sub>4</sub> and #4-CuBi<sub>2</sub>O<sub>4</sub> photocathodes. The lower value of the R<sub>ct</sub> for the #2-CuBi<sub>2</sub>O<sub>4</sub> photocathode suggests substantially higher charge transfer properties, as shown in the Nyquist plots (Figure 5a and Table S1) [36,37]. The inset in Figure 5a shows the equivalent circuit model used in the EIS profiles. The sheet resistance (R<sub>S</sub>), charge transfer resistance (R<sub>ct</sub>), and constant phase element (CPE) correspond to those at the interface between the electrode and electrolyte, as presented in Table S1. The charge-transfer resistances of the #1-CuBi<sub>2</sub>O<sub>4</sub>, #2-CuBi<sub>2</sub>O<sub>4</sub>, and #4-CuBi<sub>2</sub>O<sub>4</sub> photocathodes obtained from fitting were 1823.45, 850.37, and 1467.29  $\Omega/cm^2$ , respectively (Table S1), indicating a decrease in R<sub>ct</sub> and the lowest arc diameter. Moreover, this suggests that the charge transport properties of these photocathodes were excellent.

Mott–Schottky measurements were performed to estimate the acceptor density ( $N_A$ ) and flat band potential ( $V_{fb}$ ), which are two important factors for improving the PEC performance of the #1-CuBi<sub>2</sub>O<sub>4</sub>, #2-CuBi<sub>2</sub>O<sub>4</sub>, and #4-CuBi<sub>2</sub>O<sub>4</sub> photocathodes. The Mott–Schottky plots (Figure 5b) shows a negative slope for the CuBi<sub>2</sub>O<sub>4</sub> photocathodes, suggesting the semiconductor's p-type nature [38,39]. The slope of the Mott–Schottky plot was used

to calculate the acceptor density (N<sub>A</sub>). We estimated the acceptor density (N<sub>A</sub>) and flat band potential values from the Mott–Schottky plot (see Table S1). Further, the flat band potentials were found to be 1.34, 1.27, and 1.29 V vs. RHE for the #1-CuBi<sub>2</sub>O<sub>4</sub>, #2-CuBi<sub>2</sub>O<sub>4</sub>, and #4-CuBi<sub>2</sub>O<sub>4</sub> photocathodes, respectively, which are close to the previously reported values [40–42]. The slope of #2-CuBi<sub>2</sub>O<sub>4</sub> was smaller than that of the #1-CuBi<sub>2</sub>O<sub>4</sub> and #4-CuBi<sub>2</sub>O<sub>4</sub> photocathodes. Thus, #2-CuBi<sub>2</sub>O<sub>4</sub> has a higher acceptor density, which is conducive to improving the PEC performance.



**Figure 5.** (a) Nyquist and (b) Mott–Schottky plots of the #1–CuBi<sub>2</sub>O<sub>4</sub>, #2–CuBi<sub>2</sub>O<sub>4</sub>, and #4–CuBi<sub>2</sub>O<sub>4</sub> photocathodes. Under 100 mW/cm<sup>2</sup> illumination, the electrolyte was a 0.5 M aqueous solution of Na<sub>2</sub>SO<sub>4</sub>.

# 3.4. Effect of $H_2O_2$

The water splitting performance of the #2-CuBi<sub>2</sub>O<sub>4</sub> photocathodes was investigated using  $H_2O_2$  as an electron scavenger to assess their hydrogen generation capacity.  $H_2O_2$ was added to the electrolyte as an electron scavenger to test the CuBi<sub>2</sub>O<sub>4</sub> photocathodes without limitations on the reaction kinetics, which would be the case for proton reduction. In the presence of  $H_2O_2$  as an electron scavenger, the photocurrent density can be increased to ~1.2 mA/cm<sup>2</sup> at 0.3 V vs. RHE. As shown in Figure 6a, by adding  $H_2O_2$  (1/12.5 in volume to the electrolyte), the photocurrent increases substantially. Figure 6b shows that the semicircle for the #2-CuBi2O4 photocathode with  $H_2O_2$  as a scavenger is lower than that without a scavenger, suggesting substantially superior charge transfer properties. As shown in Figure 6c, the slope of #2-CuBi<sub>2</sub>O<sub>4</sub> with H<sub>2</sub>O<sub>2</sub> as an electron scavenger is lower than that without a scavenger, indicating that the addition of  $H_2O_2$  enhances the acceptor density, resulting in improved PEC performance. As an effective electron scavenger,  $H_2O_2$ is expected to eliminate surface recombination and overcome limitations in the reaction kinetics at the semiconductor-liquid interface. The electron scavenger  $(H_2O_2)$  leads to rapid electron transfer from the CuBi<sub>2</sub>O<sub>4</sub> photocathodes to H<sub>2</sub>O<sub>2</sub>, thereby enhancing the PEC performance [28,41,43]. Open-circuit potential analysis was performed to investigate charge carrier separation in the #2-CuBi<sub>2</sub>O<sub>4</sub> photocathode with and without H<sub>2</sub>O<sub>2</sub> as a scavenger.  $\triangle OCP$  was higher for the #2-CuBi<sub>2</sub>O<sub>4</sub> photocathode with H<sub>2</sub>O<sub>2</sub> than for the #2-CuBi2O4 photocathode without H<sub>2</sub>O<sub>2</sub> (Figure 6d). This can be attributed to the improved reaction kinetics by the suppression of recombination after light irradiation [44,45].

Figure 7 shows the complete band diagram for the CuBi<sub>2</sub>O<sub>4</sub> photocathode considering the experimentally established characteristics of the UV–vis and Mott–Schottky measurements. The band diagram of the drop-deposited #2-CuBi<sub>2</sub>O<sub>4</sub> photocathode is shown in Figure 7. Clearly, the valence band (VB) of CuBi<sub>2</sub>O<sub>4</sub> is close to the water oxidation potential. Based on an estimated bandgap of 1.75 eV, we estimated the location of the conduction band (CB) to be ~0.48 V vs. RHE, which is more negative than the water reduction potential for hydrogen generation. In other words, the photoexcited electrons in the CB of the CuBi<sub>2</sub>O<sub>4</sub> thin films can thermodynamically convert protons to hydrogen. The efficient synthesis

of  $H_2$  by PEC water splitting requires the device to use visible light. Moreover, water is reduced on the surface of p-type semiconductor materials under visible light, whereas it is oxidized at the counter electrode.



**Figure 6.** (a) Photocurrent response, (b) Nyquist, (c) Mott–Schottky plots, and (d) Open-circuit potential (OCP) measurements of the #2-CuBi<sub>2</sub>O<sub>4</sub> photocathodes with and without H<sub>2</sub>O<sub>2</sub>. Under 100 mW/cm<sup>2</sup> illumination, the electrolyte was a 0.5 M aqueous solution of Na<sub>2</sub>SO<sub>4</sub>.



Figure 7. The mechanism and band alignment of CuBi<sub>2</sub>O<sub>4</sub> photocathodes.

# 4. Conclusions

In this study, a CuBi<sub>2</sub>O<sub>4</sub> photocathode was successfully prepared using a simple and low-cost drop casting method. The deposition layer was optimized using different drop casting cycles to obtain the highest photocurrent density in the CuBi<sub>2</sub>O<sub>4</sub> photocathode. At the optimal time of the drop casting of the CuBi<sub>2</sub>O<sub>4</sub> photocathode, the photocurrent density was ~0.6 mA/cm<sup>2</sup> at 0.3 V vs. RHE under 100 mW/cm<sup>2</sup> illumination. The CuBi<sub>2</sub>O<sub>4</sub> photocathode exhibited a high photocurrent density of up to 1.2 mA/cm<sup>2</sup> at 0.3 V vs. RHE with H<sub>2</sub>O<sub>2</sub> as a sacrificial agent. Furthermore, Mott–Schottky and impedance measurements were performed to evaluate the acceptor density and charge transfer resistance of the CuBi<sub>2</sub>O<sub>4</sub> photocathode. This study demonstrates that the semiconductors can significantly enhance the performance of metal oxide-based photocathodes toward an efficient PEC water splitting system.

**Supplementary Materials:** The following supporting information can be downloaded at: https://www.mdpi.com/article/10.3390/inorganics11040147/s1. Figure S1: Raman spectra; Figure S2: High-resolution XPS of Cu2p and O1s; Figure S3: EDX spectra of the CuBi<sub>2</sub>O<sub>4</sub> photocathode; Figure S4: Inverse fast Fourier transform (IFFT) of CuBi<sub>2</sub>O<sub>4</sub>; Figure S5: SEM cross-section; Table S1: PEC parameters of the CuBi<sub>2</sub>O<sub>4</sub> photocathodes.

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### References

- Tayebi, M.; Lee, B.-K. Recent advances in BiVO<sub>4</sub> semiconductor materials for hydrogen production using photoelectrochemical water splitting. *Renew. Sustain. Energy Rev.* 2019, 111, 332–343. [CrossRef]
- Dashtian, K.; Shahbazi, S.; Tayebi, M.; Masoumi, Z. A review on metal-organic frameworks photoelectrochemistry: A headlight for future applications. *Coord. Chem. Rev.* 2021, 445, 214097. [CrossRef]
- Raghavan, S.S.; Andrews, N.G.; Sellappan, R. Carbon-Protected BiVO<sub>4</sub>—Cu<sub>2</sub>O Thin Film Tandem Cell for Solar Water Splitting Applications. *Catalysts* 2023, 13, 144. [CrossRef]
- Lee, D.J.; Kumar, G.M.; Ganesh, V.; Jeon, H.C.; Kim, D.Y.; Kang, T.W.; Ilanchezhiyan, P. Novel Nanoarchitectured Cu<sub>2</sub>Te as a Photocathodes for Photoelectrochemical Water Splitting Applications. *Nanomaterials* 2022, 12, 3192. [CrossRef]
- Fominski, V.; Demin, M.; Fominski, D.; Romanov, R.; Rubinkovskaya, O.; Shvets, P.; Goikhman, A. Pulsed Laser Phosphorus Doping and Nanocomposite Catalysts Deposition in Forming a-MoSx/NP-Mo//n+p-Si Photocathodes for Efficient Solar Hydrogen Production. *Nanomaterials* 2022, 12, 2080. [CrossRef]
- Tayebi, M.; Masoumi, Z.; Seo, B.; Li, C.-S.; Kim, H.-G.; Lee, B.-K. Efficient and Stable MoOX@Mo-BiVO<sub>4</sub> Photoanodes for Photoelectrochemical Water Oxidation: Optimization and Understanding. ACS Appl. Energy Mater. 2022, 5, 11568–11580. [CrossRef]
- Pan, L.; Kim, J.H.; Mayer, M.T.; Son, M.-K.; Ummadisingu, A.; Lee, J.S.; Hagfeldt, A.; Luo, J.; Grätzel, M. Boosting the performance of Cu<sub>2</sub>O photocathodes for unassisted solar water splitting devices. *Nat. Catal.* 2018, 1, 412–420. [CrossRef]
- 8. Wang, X.; Yu, H.; Wu, S.; Wei, X. Field enhanced GaN photocathode and a proposed implementation method. *Optik* 2017, 144, 281–288. [CrossRef]
- 9. Hsu, C.-Y.; Chen, W.-T.; Chen, Y.-C.; Wei, H.-Y.; Yen, Y.-S.; Huang, K.-C.; Ho, K.-C.; Chu, C.-W.; Lin, J.T. Charge transporting enhancement of NiO photocathodes for p-type dye-sensitized solar cells. *Electrochim. Acta* 2012, *66*, 210–215. [CrossRef]

- Ida, S.; Yamada, K.; Matsunaga, T.; Hagiwara, H.; Matsumoto, Y.; Ishihara, T. Preparation of p-Type CaFe<sub>2</sub>O<sub>4</sub> Photocathodes for Producing Hydrogen from Water. J. Am. Chem. Soc. 2010, 132, 17343–17345. [CrossRef]
- 11. Joshi, U.A.; Maggard, P.A. CuNb<sub>3</sub>O<sub>8</sub>: A p-Type Semiconducting Metal Oxide Photoelectrode. *J. Phys. Chem. Lett.* **2012**, 3, 1577–1581. [CrossRef]
- 12. Cheng, X.; Ding, J.; Wu, Y.; Liu, H.; Dawson, G. The photocathodic properties of a Fe<sub>2</sub>O<sub>3</sub> wrapped CuFeO<sub>2</sub> layer on ITO glass for water splitting. *Chem. Phys.* **2018**, *513*, 241–245. [CrossRef]
- 13. Yu, Q.; Meng, X.; Wang, T.; Li, P.; Liu, L.; Chang, K.; Liu, G.; Ye, J. A highly durable p-LaFeO<sub>3</sub>/n-Fe<sub>2</sub>O<sub>3</sub> photocell for effective water splitting under visible light. *Chem. Commun.* **2015**, *51*, 3630–3633. [CrossRef] [PubMed]
- Cooper, J.K.; Zhang, Z.; Roychoudhury, S.; Jiang, C.-M.; Gul, S.; Liu, Y.-S.; Dhall, R.; Ceballos, A.; Yano, J.; Prendergast, D.; et al. CuBi<sub>2</sub>O<sub>4</sub>: Electronic Structure, Optical Properties, and Photoelectrochemical Performance Limitations of the Photocathode. *Chem. Mater.* 2021, *33*, 934–945. [CrossRef]
- Cao, D.; Nasori, N.; Wang, Z.; Mi, Y.; Wen, L.; Yang, Y.; Qu, S.; Wang, Z.; Lei, Y. p-Type CuBi<sub>2</sub>O<sub>4</sub>: An easily accessible photocathodic material for high-efficiency water splitting. *J. Mater. Chem. A* 2016, *4*, 8995–9001. [CrossRef]
- 16. Berglund, S.P.; Abdi, F.F.; Bogdanoff, P.; Chemseddine, A.; Friedrich, D.; van de Krol, R. Comprehensive Evaluation of CuBi<sub>2</sub>O<sub>4</sub> as a Photocathode Material for Photoelectrochemical Water Splitting. *Chem. Mater.* **2016**, *28*, 4231–4242. [CrossRef]
- 17. Hahn, N.T.; Holmberg, V.C.; Korgel, B.A.; Mullins, C.B. Electrochemical Synthesis and Characterization of p-CuBi<sub>2</sub>O<sub>4</sub> Thin Film Photocathodes. *J. Phys. Chem. C* **2012**, *116*, 6459–6466. [CrossRef]
- Sullivan, I.; Zoellner, B.; Maggard, P.A. Copper(I)-Based p-Type Oxides for Photoelectrochemical and Photovoltaic Solar Energy Conversion. *Chem. Mater.* 2016, 28, 5999–6016. [CrossRef]
- 19. Strömberg, A.; Yuan, Y.; Li, F.; Manavaimaran, B.; Lourdudoss, S.; Zhang, P.; Sun, Y. Heteroepitaxial Growth of GaP Photocathode by Hydride Vapor Phase Epitaxy for Water Splitting and CO<sub>2</sub> Reduction. *Catalysts* **2022**, *12*, 1482. [CrossRef]
- MKumar; Meena, B.; Subramanyam, P.; Suryakala, D.; Subrahmanyam, C. Emerging Copper-Based Semiconducting Materials for Photocathodic Applications in Solar Driven Water Splitting. *Catalysts* 2022, 12, 1198.
- 21. Yuvaraj, S.; Karthikeyan, K.; Kalpana, D.; Lee, Y.S.; Selvan, R.K. Surfactant-free hydrothermal synthesis of hierarchically structured spherical CuBi<sub>2</sub>O<sub>4</sub> as negative electrodes for Li-ion hybrid capacitors. *J. Colloid Interface Sci.* **2016**, 469, 47–56. [CrossRef]
- Zhang, J.; Jiang, Y.; Gao, W.; Hao, H. Synthesis and visible photocatalytic activity of new photocatalyst MBi<sub>2</sub>O<sub>4</sub>(M = Cu, Zn). J. Mater. Sci. Mater. Electron. 2015, 26, 1866–1873. [CrossRef]
- Elaziouti, A.; Laouedj, N.; Bekka, A. Synergetic effects of Sr-doped CuBi<sub>2</sub>O<sub>4</sub> catalyst with enhanced photoactivity under UVA– light irradiation. *Environ. Sci. Pollut. Res.* 2016, 23, 15862–15876. [CrossRef] [PubMed]
- Arai, T.; Yanagida, M.; Konishi, Y.; Iwasaki, Y.; Sugihara, H.; Sayama, K. Efficient Complete Oxidation of Acetaldehyde into CO<sub>2</sub> over CuBi<sub>2</sub>O<sub>4</sub>/WO<sub>3</sub> Composite Photocatalyst under Visible and UV Light Irradiation. *J. Phys. Chem. C* 2007, 111, 7574–7577. [CrossRef]
- Xu, N.; Li, F.; Gao, L.; Hu, H.; Hu, Y.; Long, X.; Ma, J.; Jin, J. Polythiophene coated CuBi<sub>2</sub>O<sub>4</sub> networks: A porous inorganic–organic hybrid heterostructure for enhanced photoelectrochemical hydrogen evolution. *Int. J. Hydrogen Energy* 2018, 43, 2064–2072. [CrossRef]
- 26. Xu, Y.; Jian, J.; Li, F.; Liu, W.; Jia, L.; Wang, H. Porous CuBi<sub>2</sub>O<sub>4</sub> photocathodes with rationally engineered morphology and composition towards high-efficiency photoelectrochemical performance. *J. Mater. Chem. A* **2019**, *7*, 21997–22004. [CrossRef]
- 27. Zhu, X.; Guan, Z.; Wang, P.; Zhang, Q.; Dai, Y.; Huang, B. Amorphous TiO<sub>2</sub>-modified CuBi<sub>2</sub>O<sub>4</sub> Photocathode with enhanced photoelectrochemical hydrogen production activity. *Chin. J. Catal.* **2018**, *39*, 1704–1710. [CrossRef]
- Wang, F.; Septina, W.; Chemseddine, A.; Abdi, F.F.; Friedrich, D.; Bogdanoff, P.; van de Krol, R.; Tilley, S.D.; Berglund, S.P. Gradient Self-Doped CuBi<sub>2</sub>O<sub>4</sub> with Highly Improved Charge Separation Efficiency. J. Am. Chem. Soc. 2017, 139, 15094–15103. [CrossRef]
- Shah, A.K.; Sahu, T.K.; Banik, A.; Gogoi, D.; Peela, N.R.; Qureshi, M. Reduced graphene oxide modified CuBi<sub>2</sub>O<sub>4</sub> as an efficient and noble metal free photocathode for superior photoelectrochemical hydrogen production. *Sustain. Energy Fuels* 2019, 3, 1554–1561. [CrossRef]
- 30. Kang, D.; Hill, J.C.; Park, Y.; Choi, K.-S. Photoelectrochemical Properties and Photostabilities of High Surface Area CuBi<sub>2</sub>O<sub>4</sub> and Ag-Doped CuBi<sub>2</sub>O<sub>4</sub> Photocathodes. *Chem. Mater.* **2016**, *28*, 4331–4340. [CrossRef]
- Lee, W.-H.; Kang, J.; Park, H.S.; Nam, K.M.; Cho, S.K. Photoelectrochemical response of Au-decorated CuBi<sub>2</sub>O<sub>4</sub> photocathode in bicarbonate solution. *J. Electroanal. Chem.* 2019, 838, 172–177. [CrossRef]
- Jiang, Z.; Geng, H.; Cai, X.; Mao, L.; Zhao, Y.; Gu, X. Preparation of CuBi<sub>2</sub>O<sub>4</sub> photocathodes for overall water splitting under visible light irradiation. *Mater. Sci. Semicond. Process.* 2021, 134, 105989. [CrossRef]
- 33. Kim, N.-W.; Choi, B.-U.; Yu, H.; Ryu, S.; Oh, J. Formation of high-density CuBi<sub>2</sub>O<sub>4</sub> thin film photocathodes with polyvinylpyrrolidone-metal interaction. *Opt. Express* **2019**, *27*, A171–A183. [CrossRef] [PubMed]
- 34. Reddy, D.A.; Kim, Y.; Varma, P.; Gopannagari, M.; Reddy, K.A.J.; Hong, D.H.; Song, I.; Kumar, D.P.; Kim, T.K. Inverse Opal CuBi<sub>2</sub>O<sub>4</sub> Photocathodes for Robust Photoelectrochemical Water Splitting. *ACS Appl. Energy Mater.* **2022**, *5*, 6050–6058. [CrossRef]
- 35. Jin, J.; Hu, J.; Qu, J.; Cao, G.; Lei, Y.; Zheng, Z.; Yang, X.; Li, C.M. Reaction Kinetics of Photoelectrochemical CO<sub>2</sub> Reduction on a CuBi<sub>2</sub>O<sub>4</sub>-Based Photocathode. *ACS Appl. Mater. Interfaces* **2022**, *14*, 17509–17519. [CrossRef]
- Lee, S.; Cha, S.; Myung, Y.; Park, K.; Kwak, I.H.; Kwon, I.S.; Seo, J.; Lim, S.A.; Cha, E.H.; Park, J. Orthorhombic NiSe<sub>2</sub> Nanocrystals on Si Nanowires for Efficient Photoelectrochemical Water Splitting. ACS Appl. Mater. Interfaces 2018, 10, 33198–33204. [CrossRef] [PubMed]

- Wang, X.-D.; Xu, Y.-F.; Chen, B.-X.; Ning, Z.; Chen, H.-Y.; Kuang, D.-B.; Su, C.-Y. 3D Cathodes of Cupric Oxide Nanosheets Coated onto Macroporous Antimony-Doped Tin Oxide for Photoelectrochemical Water Splitting. *ChemSusChem* 2016, *9*, 3012–3018. [CrossRef] [PubMed]
- 38. Varunkumar, K.; Sellappan, R. Photoelectrochemical behaviour of CuBi<sub>2</sub>O<sub>4</sub>@MoS<sub>2</sub> photocathode for solar water splitting. *Mater. Chem. Phys.* **2021**, *261*, 124245. [CrossRef]
- Choi, Y.-H.; Yang, K.D.; Kim, D.-H.; Nam, K.T.; Hong, S.-H. p-Type CuBi<sub>2</sub>O<sub>4</sub> thin films prepared by flux-mediated one-pot solution process with improved structural and photoelectrochemical characteristics. *Mater. Lett.* 2017, 188, 192–196. [CrossRef]
- Park, H.S.; Lee, C.-Y.; Reisner, E. Photoelectrochemical reduction of aqueous protons with a CuO | CuBi<sub>2</sub>O<sub>4</sub> heterojunction under visible light irradiation. *Phys. Chem. Chem. Phys.* 2014, *16*, 22462–22465. [CrossRef]
- Song, A.; Plate, P.; Chemseddine, A.; Wang, F.; Abdi, F.F.; Wollgarten, M.; van de Krol, R.; Berglund, S.P. Cu:NiO as a hole-selective back contact to improve the photoelectrochemical performance of CuBi<sub>2</sub>O<sub>4</sub> thin film photocathodes. *J. Mater. Chem. A* 2019, 7, 9183–9194. [CrossRef]
- 42. Monny, S.A.; Zhang, L.; Wang, Z.; Luo, B.; Konarova, M.; Du, A.; Wang, L. Fabricating highly efficient heterostructured CuBi<sub>2</sub>O<sub>4</sub> photocathodes for unbiased water splitting. *J. Mater. Chem. A* **2020**, *8*, 2498–2504. [CrossRef]
- Jeong, H.W.; Zsigmond, T.S.; Samu, G.F.; Janáky, C. Sacrificial Agent Gone Rogue: Electron-Acceptor-Induced Degradation of CsPbBr<sub>3</sub> Photocathodes. ACS Energy Lett. 2022, 7, 417–424. [CrossRef]
- 44. Liu, R.; Zheng, Z.; Spurgeon, J.; Yang, X. Enhanced photoelectrochemical water-splitting performance of semiconductors by surface passivation layers. *Energy Environ. Sci.* 2014, 7, 2504–2517. [CrossRef]
- Li, J.; Griep, M.; Choi, Y.; Chu, D. Photoelectrochemical overall water splitting with textured CuBi<sub>2</sub>O<sub>4</sub> as a photocathode. *Chem. Commun.* 2018, 54, 3331–3334. [CrossRef] [PubMed]

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